

100301

Low Power Triple 5-Input OR/NOR Gate

General Description

The 100301 is a monolithic triple 5-input OR/NOR gate. All inputs have 50 kΩ pull-down resistors and all outputs are buffered.

Features

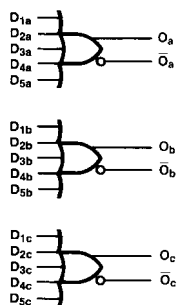
- 23% power reduction of the 100101
- 2000V ESD protection
- Pin/function compatible with 100101
- Voltage compensated operating range = -4.2V to -5.7V
- Available to industrial grade temperature range (PLCC package only)

Ordering Code:

Order Number	Package Number	Package Description
100301SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
100301PC	N24E	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.400 Wide
100301QC	V28A	28-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.450 Square
100301QI	V28A	28-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.450 Square Industrial Temperature Range (-40°C to +85°C)

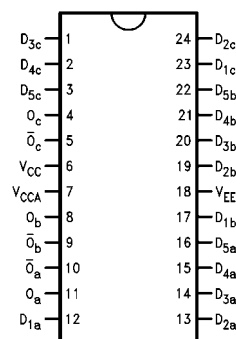
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

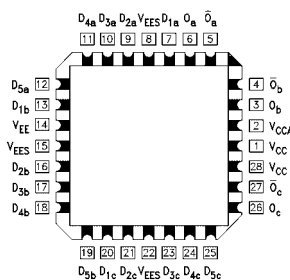


Connection Diagrams

24-Pin DIP/SOIC



28-Pin PLCC



Pin Descriptions

Pin Names	Description
D_{1a}, D_{1b}, D_{1c}	Data Inputs
O_a, O_b, O_c	Data Outputs
$\overline{O_a}, \overline{O_b}, \overline{O_c}$	Complementary Data Outputs

Truth Table

Inputs					Outputs	
D _{1a} , D _{1b} , D _{1c}	D _{2a} , D _{2b} , D _{2c}	D _{3a} , D _{3b} , D _{3c}	D _{4a} , D _{4b} , D _{4c}	D _{5a} , D _{5b} , D _{5c}	O _a , O _b , O _c	$\overline{O_a}$, $\overline{O_b}$, $\overline{O_c}$
L	L	L	L	L	L	H
L	L	L	L	H	H	L
L	L	L	H	L	H	L
L	L	L	H	H	H	L
L	L	H	L	L	H	L
L	L	H	L	H	H	L
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H	H	H	L	L	H	L
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H	H	H	H	L	H	L
H	H	H	H	H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level

Absolute Maximum Ratings(Note 1)

Storage Temperature (T_{STG})	-65°C to +150°C
Maximum Junction Temperature (T_J)	+150°C
V_{EE} Pin Potential to Ground Pin	-7.0V to +0.5V
Input Voltage (DC)	V_{EE} to +0.5V
Output Current (DC Output HIGH)	-50 mA
ESD (Note 2)	≥2000V

Recommended Operating Conditions

Case Temperature (T_C)	
Commercial	0°C to +85°C
Industrial	-40°C to +85°C
Supply Voltage (V_{EE})	-5.7V to -4.2V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum rating. The "recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: ESD testing conforms to MIL-STD-883, Method 3015.

Commercial Version**DC Electrical Characteristics** (Note 3)

$V_{EE} = -4.2V$ to $-5.7V$, $V_{CC} = V_{CCA} = GND$, $T_C = 0^\circ C$ to $+85^\circ C$

Symbol	Parameter	Min	Typ	Max	Units	Conditions	
V_{OH}	Output HIGH Voltage	-1025	-955	-870	mV	$V_{IN} = V_{IH(Max)}$ or $V_{IL(Min)}$	Loading with 50Ω to -2.0V
V_{OL}	Output LOW Voltage	-1830	-1705	-1620	mV		
V_{OHC}	Output HIGH Voltage	-1035			mV	$V_{IN} = V_{IH(Min)}$ or $V_{IL(Max)}$	Loading with 50Ω to -2.0V
V_{OLC}	Output LOW Voltage			-1610	mV		
V_{IH}	Input HIGH Voltage	-1165		-870	mV	Guaranteed HIGH Signal for All Inputs	
V_{IL}	Input LOW Voltage	-1830		-1475	mV	Guaranteed LOW Signal for All Inputs	
I_{IL}	Input LOW Current	0.50			μA	$V_{IN} = V_{IL(Min)}$	
I_{IH}	Input HIGH Current			240	μA	$V_{IN} = V_{IH(Max)}$	
I_{EE}	Power Supply Current	-29	-17	-15	mA	Inputs OPEN	

Note 3: The specified limits represent the "worst case" value for the parameter. Since these values normally occur at the temperature extremes, additional noise immunity and guardbanding can be achieved by decreasing the allowable system operating ranges. Conditions for testing shown in the tables are chosen to guarantee operation under "worst case" conditions.

DIP AC Electrical Characteristics

$V_{EE} = -4.2V$ to $-5.7V$, $V_{CC} = V_{CCA} = GND$

Symbol	Parameter	$T_C = 0^\circ C$		$T_C = +25^\circ C$		$T_C = +85^\circ C$		Units	Conditions
		Min	Max	Min	Max	Min	Max		
t_{PLH}	Propagation Delay	0.50	1.10	0.50	1.15	0.50	1.20	ns	Figures 1, 2 (Note 4)
t_{PHL}	Data to Output								
t_{TLH}	Transition Time	0.40	1.20	0.40	1.20	0.40	1.20	ns	Figures 1, 2
t_{THL}	20% to 80%, 80% to 20%								

Note 4: The propagation delay specified is for single output switching. Delays may vary up to 100 ps with multiple outputs switching.

Commercial Version (Continued) SOIC and PLCC AC Electrical Characteristics

$V_{EE} = -4.2V$ to $-5.7V$, $V_{CC} = V_{CCA} = GND$

Symbol	Parameter	$T_C = 0^\circ C$		$T_C = +25^\circ C$		$T_C = +85^\circ C$		Units	Conditions
		Min	Max	Min	Max	Min	Max		
t_{PLH} t_{PHL}	Propagation Delay Data to Output	0.50	1.00	0.50	1.05	0.50	1.10	ns	Figures 1, 2 (Note 5)
t_{TLH} t_{THL}	Transition Time 20% to 80%, 80% to 20%	0.40	1.10	0.40	1.10	0.40	1.10	ns	Figures 1, 2
t_{OSHL}	Maximum Skew Common Edge Output-to-Output Variation Data to Output Path		240		240		240	ps	PLCC Only (Note 6)
t_{OSLH}	Maximum Skew Common Edge Output-to-Output Variation Data to Output Path		330		330		330	ps	PLCC Only (Note 6)
t_{OST}	Maximum Skew Opposite Edge Output-to-Output Variation Data to Output Path		330		330		330	ps	PLCC Only (Note 6)
t_{PS}	Maximum Skew Pin (Signal) Transition Variation Data to Output Path		230		230		230	ps	PLCC Only (Note 6)

Note 5: The propagation delay specified is for single output switching. Delays may vary up to 100 ps with multiple outputs switching.

Note 6: Output-to-Output Skew is defined as the absolute value of the difference between the actual propagation delay for any outputs within the same packaged device. The specifications apply to any outputs switching in the same direction either HIGH-to-LOW (t_{OSHL}), or LOW-to-HIGH (t_{OSLH}), or in opposite directions both HL and LH (t_{OST}). Parameters t_{OST} and t_{PS} guaranteed by design.

Industrial Version

PLCC DC Electrical Characteristics (Note 7)

$V_{EE} = -4.2V$ to $-5.7V$, $V_{CC} = V_{CCA} = GND$, $T_C = -40^\circ C$ to $+85^\circ C$

Symbol	Parameter	T _C = −40°C		T _C = 0°C to +85°C		Units	Conditions	
		Min	Max	Min	Max			
V _{OH}	Output HIGH Voltage	−1085	−870	−1025	−870	mV	V _{IN} = V _{IH(Max)}	Loading with 50Ω to −2.0V
V _{OL}	Output LOW Voltage	−1830	−1575	−1830	−1620	mV	or V _{IL(Min)}	
V _{OHC}	Output HIGH Voltage	−1095		−1035		mV	V _{IN} = V _{IH(Min)}	Loading with 50Ω to −2.0V
V _{OLC}	Output LOW Voltage		−1565		−1610	mV	or V _{IL(Max)}	
V _{IH}	Input HIGH Voltage	−1170	−870	−1165	−870	mV	Guaranteed HIGH Signal for All Inputs	
V _{IL}	Input LOW Voltage	−1830	−1480	−1830	−1475	mV	Guaranteed LOW Signal for All Inputs	
I _{IL}	Input LOW Current	0.50		0.50		μA	V _{IN} = V _{IL(Min)}	
I _{IH}	Input HIGH Current		240		240	μA	V _{IN} = V _{IH(Max)}	
I _{EE}	Power Supply Current	−29	−15	−29	−15	mA	Inputs Open	

Note 7: The specified limits represent the "worst case" value for the parameter. Since these values normally occur at the temperature extremes, additional noise immunity and guardbanding can be achieved by decreasing the allowable system operating ranges. Conditions for testing shown in the tables are chosen to guarantee operation under "worst case" conditions.

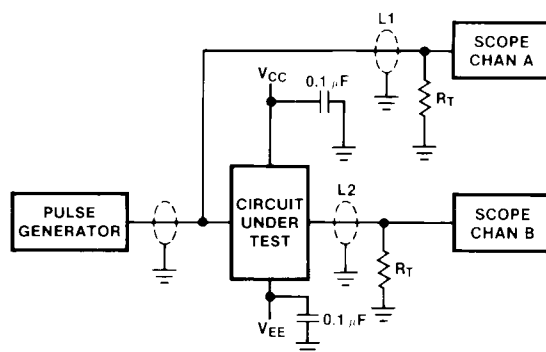
PLCC AC Electrical Characteristics

$V_{EE} = -4.2V$ to $-5.7V$, $V_{CC} = V_{CCA} = GND$

Symbol	Parameter	$T_C = -40^\circ C$		$T_C = +25^\circ C$		$T_C = +85^\circ C$		Units	Conditions
		Min	Max	Min	Max	Min	Max		
t_{PLH} t_{PHL}	Propagation Delay Data to Output	0.40	1.00	0.50	1.05	0.50	1.10	ns	Figures 1, 2 (Note 8)
t_{TLH} t_{THL}	Transition Time 20% to 80%, 80% to 20%	0.30	1.10	0.40	1.10	0.40	1.10	ns	Figures 1, 2

Note 8: The propagation delay specified is for single output switching. Delays may vary up to 100 ps with multiple outputs switching.

Test Circuitry



Notes:

$V_{CC}, V_{CCA} = +2V, V_{EE} = -2.5V$

$L1$ and $L2$ = equal length 50Ω impedance lines

$R_T = 50\Omega$ terminator internal to scope

Decoupling $0.1 \mu F$ from GND to V_{CC} and V_{EE}

All unused outputs are loaded with 50Ω to GND

C_L = Fixture and stray capacitance ≤ 3 pF

FIGURE 1. AC Test Circuit

Switching Waveforms

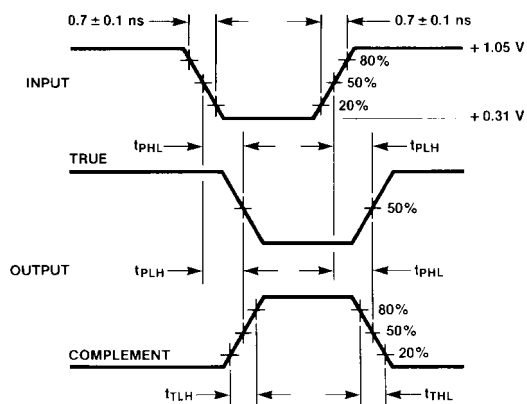
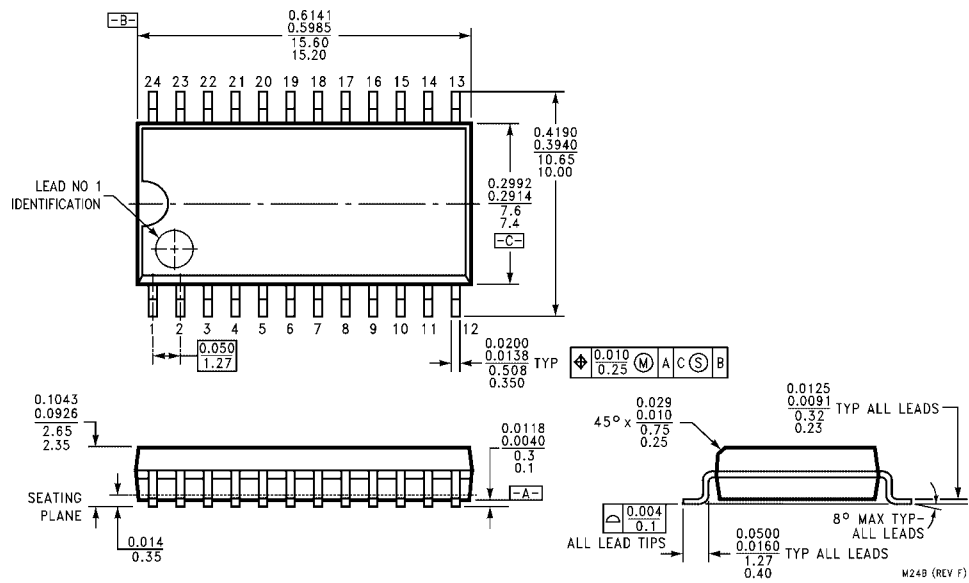
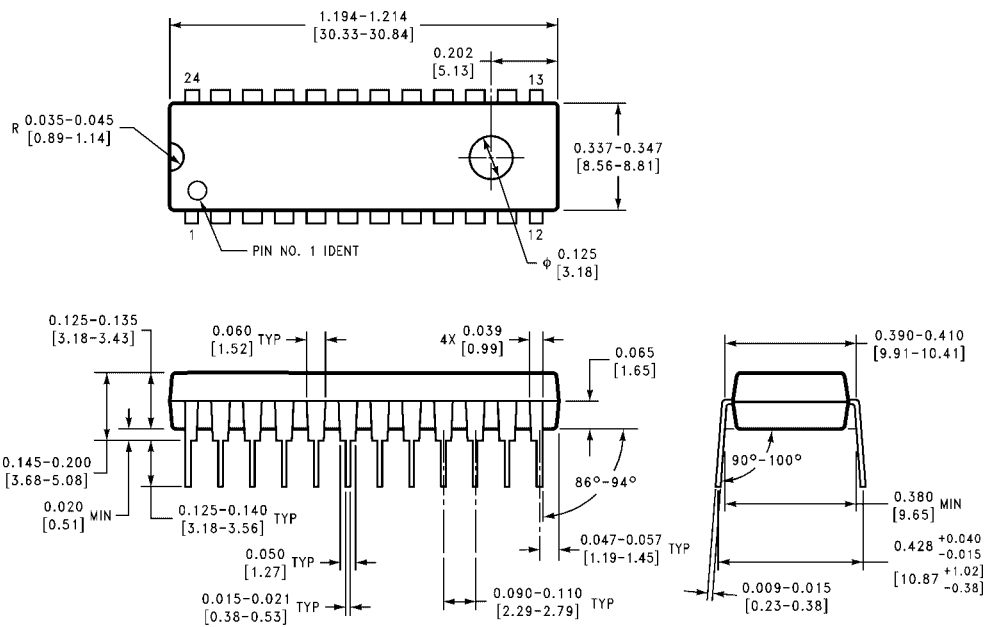


FIGURE 2. Propagation Delay and Transition Times

Physical Dimensions inches (millimeters) unless otherwise noted

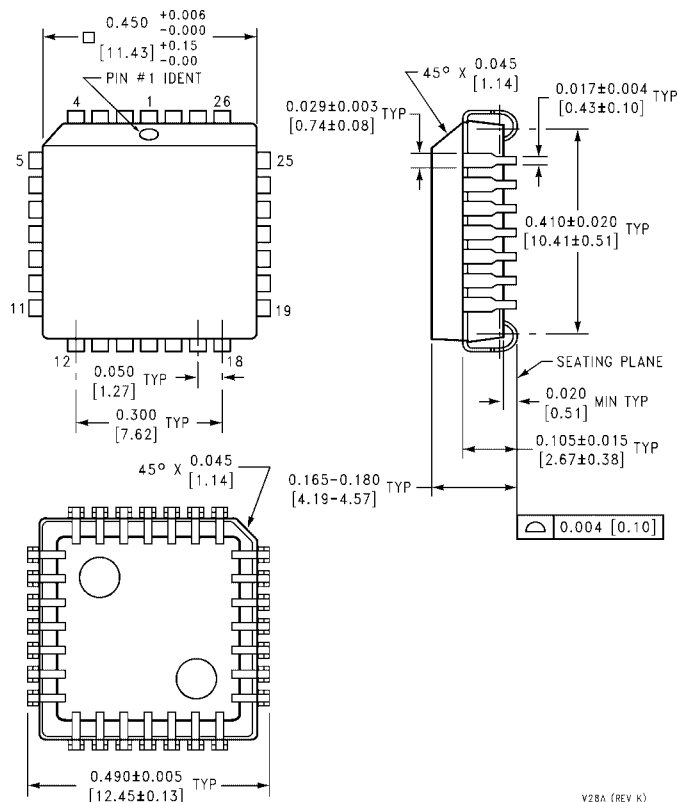


**24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B**



**24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.400 Wide
Package Number N24E**

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



**28-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.450 Square
Package Number V28A**

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